



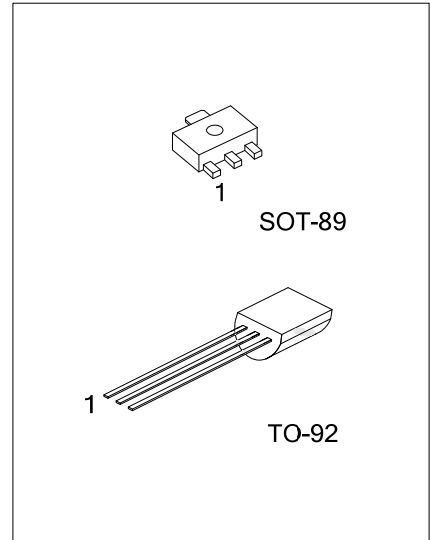
MPSA44H

NPN SILICON TRANSISTOR

HIGH VOLTAGE TRANSISTOR

FEATURES

- * Collector-Emitter Voltage: $V_{CE0}=400V$
- * Collector Current up to 300mA



ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
MPSA44HL-AB3-R	MPSA44HG-AB3-R	SOT-89	B	C	E	Tape Reel
MPSA44HL-T92-B	MPSA44HG-T92-B	TO-92	E	B	C	Tape Box
MPSA44HL-T92-K	MPSA44HG-T92-K	TO-92	E	B	C	Bulk
MPSA44HL-T92-R	MPSA44HG-T92-R	TO-92	E	B	C	Tape Reel

<p>MPSA44HL-AB3-R</p> <p>(1)Packing Type</p> <p>(2)Package Type</p> <p>(3)Lead Free</p>	<p>(1) B: Tape Box, K: Bulk, R: Tape Reel</p> <p>(2) AB3: SOT-89, T92: TO-92</p> <p>(3) G: Halogen Free, L: Lead Free</p>
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■ ABSOLUTE MAXIMUM RATING

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Base Voltage		V_{CBO}	800	V
Collector-Emitter Voltage		V_{CEO}	400	V
Emitter-Base Voltage		V_{EBO}	6	V
Collector Current		I_C	300	mA
Collector Dissipation	SOT-89	P_C	500	mW
	TO-92		625	
Junction Temperature		T_J	125	°C
Operating Temperature		T_{OPR}	-20 ~ +85	°C
Storage Temperature		T_{STG}	-40 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS ($T_J=25^\circ\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Base Breakdown Voltage	BV_{CBO}	$I_C=100\mu\text{A}, I_E=0$	800			V
Collector-Emitter Breakdown Voltage	BV_{CEO}	$I_C=1\text{mA}, I_B=0$	400			V
Emitter-Base Breakdown Voltage	BV_{EBO}	$I_E=100\mu\text{A}, I_C=0$	6			V
Collector Cutoff Current	I_{CBO}	$V_{CB}=400\text{V}, I_E=0$			0.1	μA
Collector Cutoff Current	I_{CEO}	$V_{CE}=400\text{V}, I_B=0$			0.5	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=4\text{V}, I_C=0$			0.1	μA

ON CHARACTERISTICS

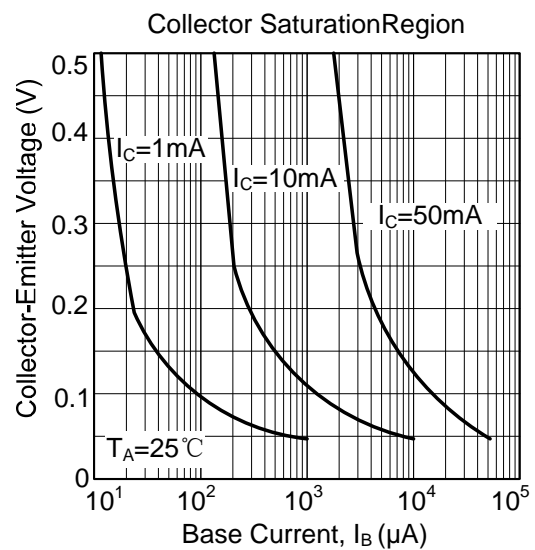
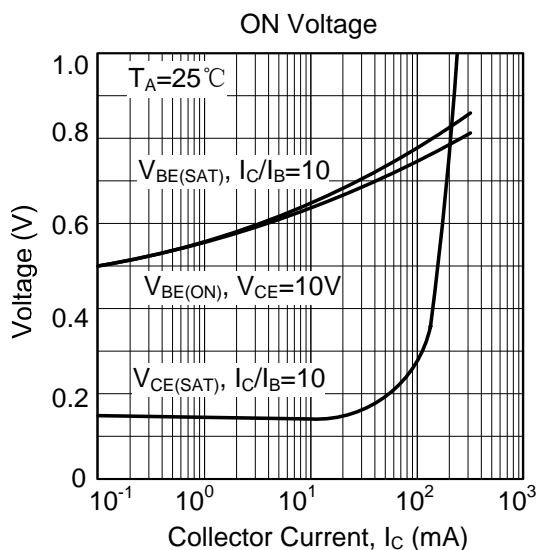
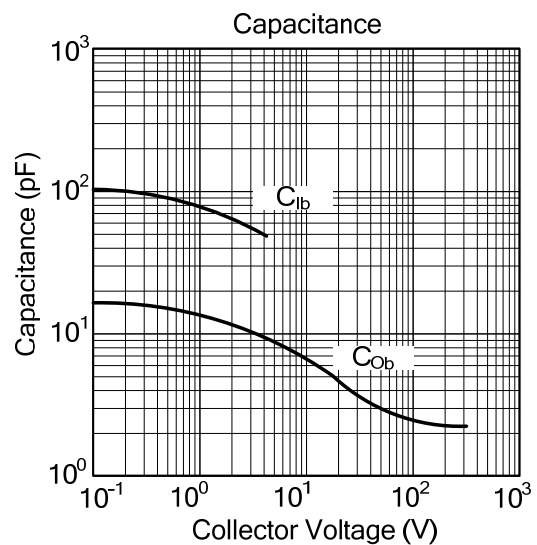
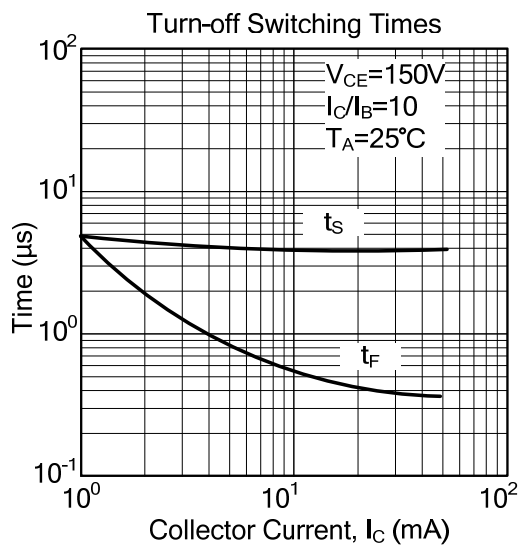
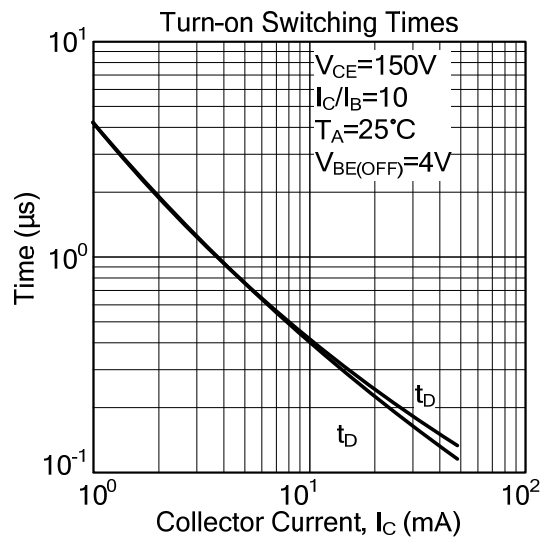
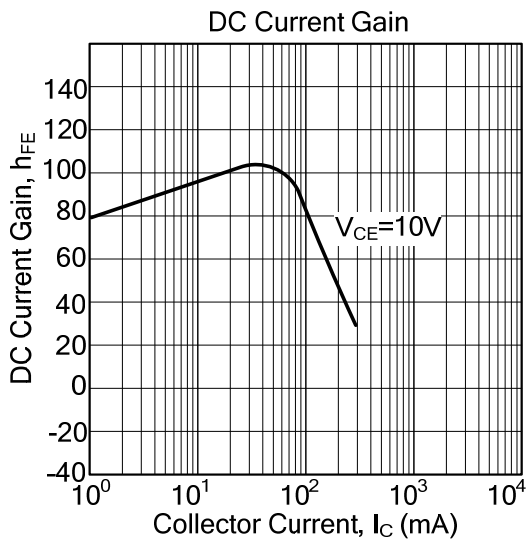
DC Current Gain (Note)	h_{FE}	$V_{CE}=10\text{V}, I_C=1\text{mA}$	40		240	
		$V_{CE}=10\text{V}, I_C=10\text{mA}$	82		240	
		$V_{CE}=10\text{V}, I_C=50\text{mA}$	45		240	
		$V_{CE}=10\text{V}, I_C=100\text{mA}$	40		240	
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	$I_C=1\text{mA}, I_B=0.1\text{mA}$			0.4	V
		$I_C=10\text{mA}, I_B=1\text{mA}$			0.5	
		$I_C=50\text{mA}, I_B=5\text{mA}$			0.75	
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	$I_C=10\text{mA}, I_B=1\text{mA}$			0.75	V

SMALL-SIGNAL CHARACTERISTICS

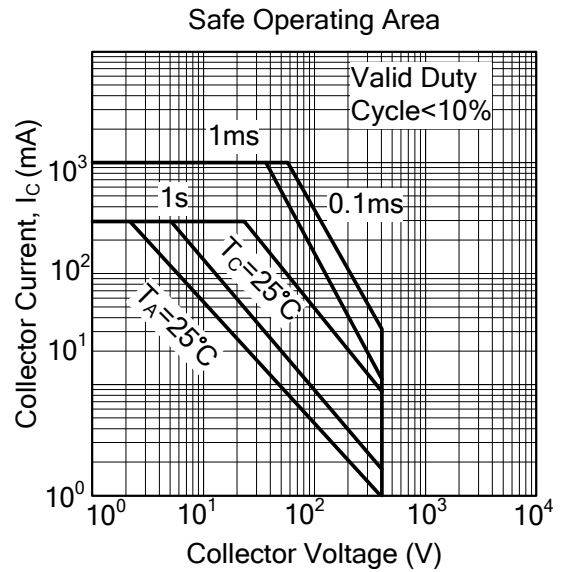
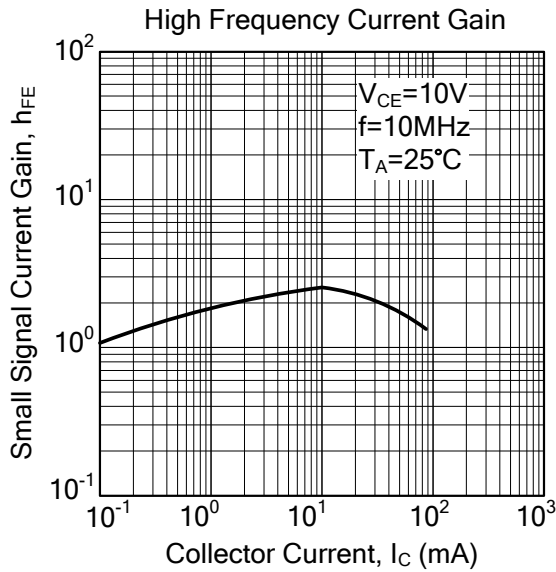
Current Gain Bandwidth Product	f_T	$V_{CE}=20\text{V}, I_C=10\text{mA}, f=100\text{MHz}$	50			MHz
Output Capacitance	C_{OB}	$V_{CB}=20\text{V}, I_E=0, f=1\text{MHz}$			7	pF

Note: Pulse test: $P_W < 300\mu\text{s}$, Duty Cycle $< 2\%$

■ TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS(Cont.)



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